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MPSL51

Amplifier Transistor PNP Silicon



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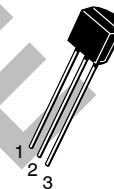
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MAXIMUM RATINGS

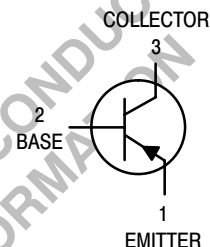
Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	-100	Vdc
Collector–Base Voltage	V_{CBO}	-100	Vdc
Emitter–Base Voltage	V_{EBO}	-4.0	Vdc
Collector Current — Continuous	I_C	-600	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$



TO-92 (TO-226AA)
CASE 29-11
STYLE 1



ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage ⁽¹⁾ ($I_C = -1.0 \text{ mAdc}, I_E = 0$)	$V_{(BR)CEO}$	-100	—	Vdc
Collector–Base Breakdown Voltage ($I_C = -100 \mu\text{Adc}, I_E = 0$)	$V_{(BR)CBO}$	-100	—	Vdc
Emitter–Base Breakdown Voltage ($I_E = -10 \mu\text{Adc}, I_C = 0$)	$V_{(BR)EBO}$	-4.0	—	Vdc
Collector Cutoff Current ($V_{CB} = -50 \text{ Vdc}, I_E = 0$)	I_{CBO}	—	-1.0	μAdc
Emitter Cutoff Current ($V_{EB} = -3.0 \text{ Vdc}, I_C = 0$)	I_{EBO}	—	-100	nAdc

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle = 2.0%.

MPSL51

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS⁽¹⁾				
DC Current Gain ⁽¹⁾ ($I_C = -50\text{ mAdc}$, $V_{CE} = -5.0\text{ Vdc}$)	h_{FE}	40	250	—
Collector – Emitter Saturation Voltage ($I_C = -10\text{ mAdc}$, $I_B = -1.0\text{ mAdc}$) ($I_C = -50\text{ mAdc}$, $I_B = -5.0\text{ mAdc}$)	$V_{CE(sat)}$	— —	-0.25 -0.30	Vdc
Base – Emitter Saturation Voltage ($I_C = -10\text{ mAdc}$, $I_B = -1.0\text{ mAdc}$) ($I_C = -50\text{ mAdc}$, $I_B = -5.0\text{ mAdc}$)	$V_{BE(sat)}$	— —	-1.2 -1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current – Gain — Bandwidth Product ($I_C = -10\text{ mAdc}$, $V_{CE} = -10\text{ Vdc}$, $f = 20\text{ MHz}$)	f_T	60	—	MHz
Output Capacitance ($V_{CB} = -10\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{obo}	—	8.0	pF
Small-Signal Current Gain ($I_C = -1.0\text{ mAdc}$, $V_{CE} = -10\text{ Vdc}$, $f = 1.0\text{ kHz}$)	h_{fe}	20	—	—

1. Pulse Test: Pulse Width = 300 μs , Duty Cycle = 2.0%.

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MPSL51

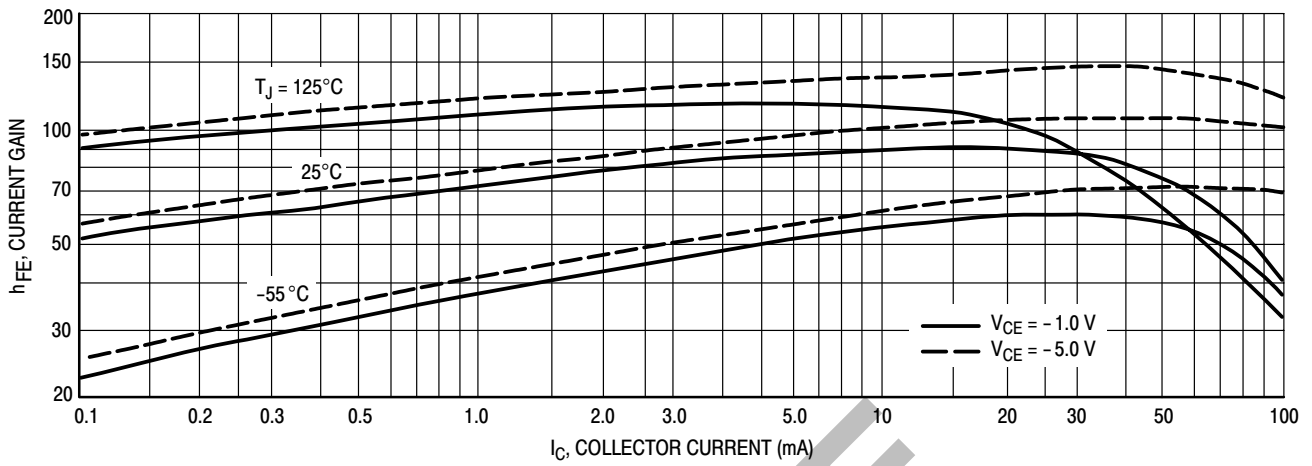


Figure 1. DC Current Gain

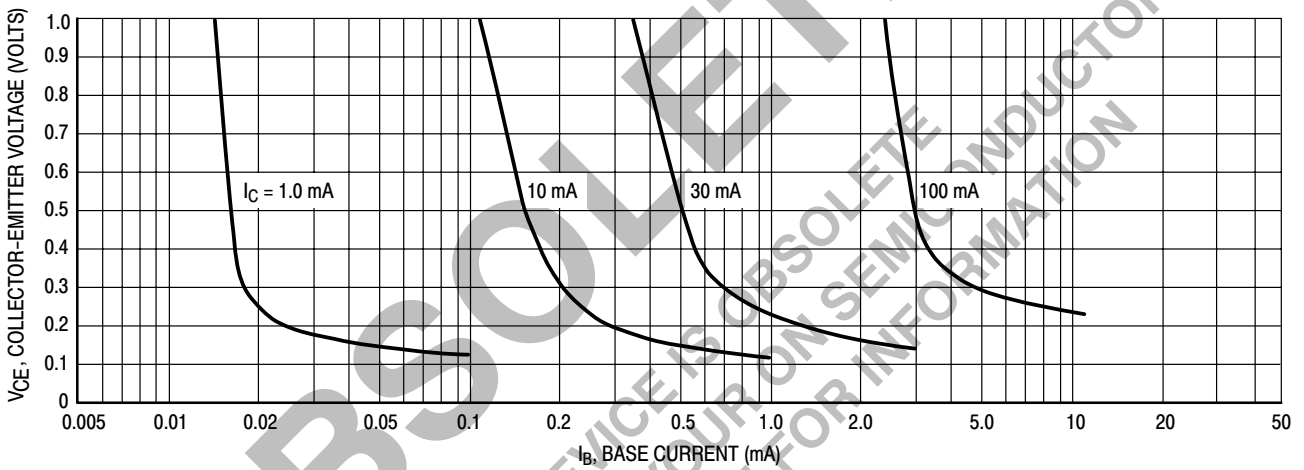


Figure 2. Collector Saturation Region

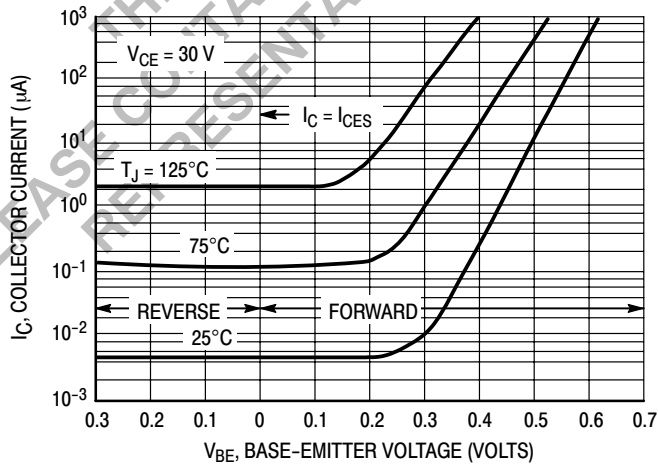


Figure 3. Collector Cut-Off Region

MP51

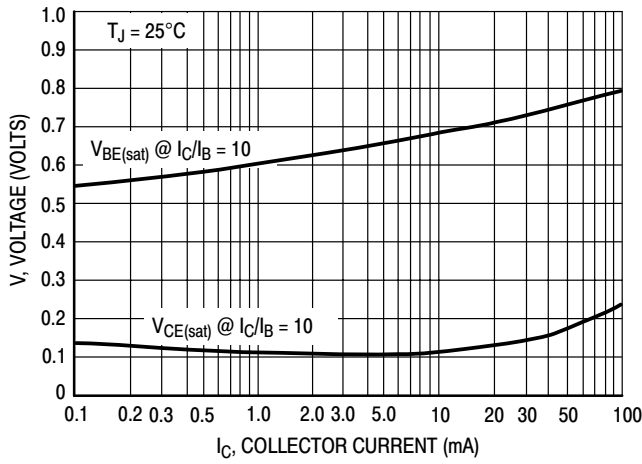


Figure 4. "On" Voltages

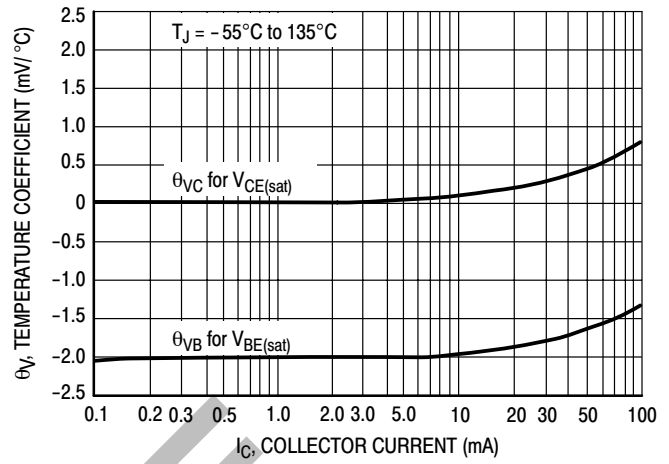


Figure 5. Temperature Coefficients

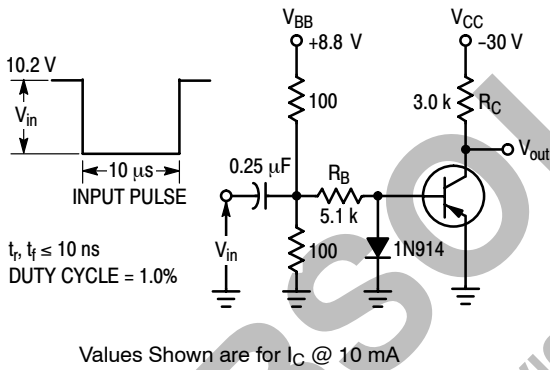


Figure 6. Switching Time Test Circuit

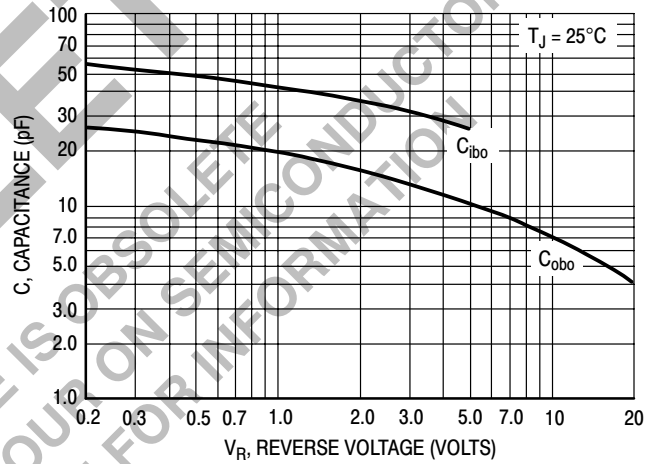


Figure 7. Capacitances

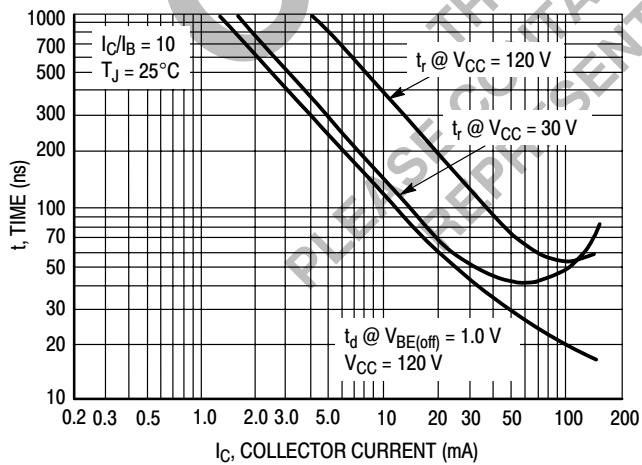


Figure 8. Turn-On Time

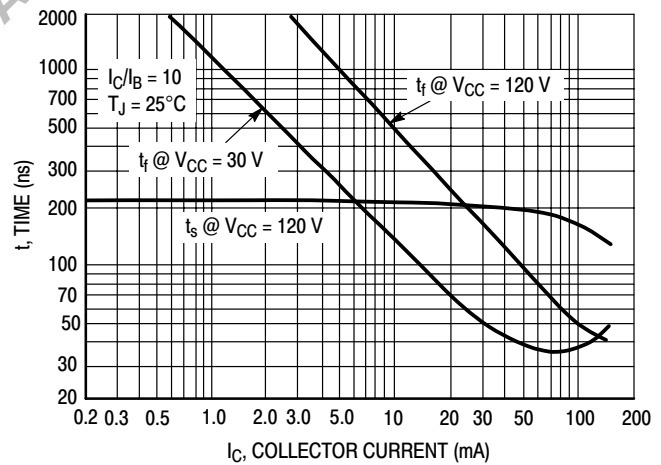
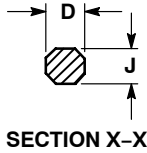
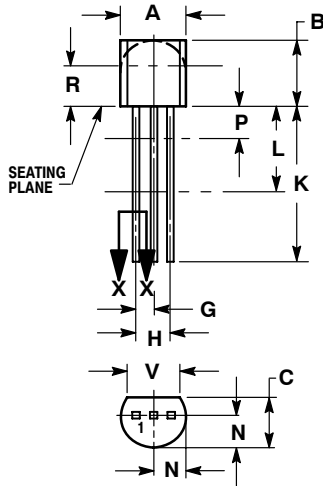


Figure 9. Turn-Off Time

MPSL51

PACKAGE DIMENSIONS

TO-92 (TO-226AA) CASE 29-11 ISSUE AL



STYLE 1:
1. EMITTER
2. BASE
3. COLLECTOR

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

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